TOSHIBA Insulated Gate Bipolar Transistor Silicon N Chanenel IGBT

## GT20J321

# High Power Switching Applications Fast Switching Applications

• The 4th generation

• Enhancement-mode

• Fast switching (FS): Operating frequency up to 50 kHz (reference)

High speed:  $t_f = 0.04 \mu s$  (typ.)

Low switching loss :  $E_{0n} = 0.40 \text{ mJ (typ.)}$ 

 $: E_{off} = 0.43 \text{ mJ (typ.)}$ 

• Low saturation voltage: VCE (sat) = 2.0 V (typ.)

• FRD included between emitter and collector

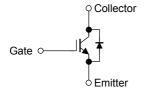
#### **Maximum Ratings (Ta = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	Ic	20	Α	
	1 ms	I <sub>CP</sub>	40		
Emitter-collector forward current	DC	I <sub>F</sub>	20	А	
	1 ms	I <sub>FM</sub>	40		
Collector power dissipation (Tc = 25°C)		PC	45	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	

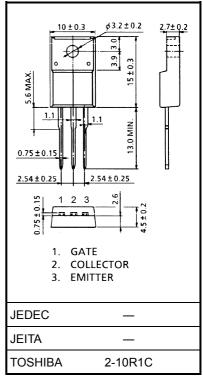
#### **Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Thermal resistance (IGBT)	R <sub>th (j-c)</sub>	2.78	°C/W
Thermal resistance (diode)	R <sub>th (j-c)</sub>	4.23	°C/W

#### **Equivalent Circuit**



Unit: mm

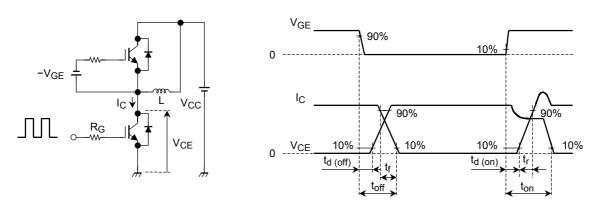


Weight: 1.7 g (typ.)

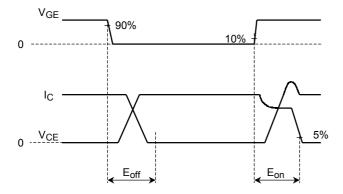
### **Electrical Characteristics (Ta = 25°C)**

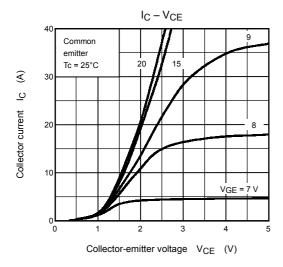
Cha	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	V <sub>GE</sub> = ±20 V, V <sub>CE</sub> = 0	_	_	±500	nA
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE</sub> (OFF)	I <sub>C</sub> = 2 mA, V <sub>CE</sub> = 5 V	3.5	_	6.5	V
Collector-emitter saturation voltage		V <sub>CE</sub> (sat)	I <sub>C</sub> = 20 A, V <sub>GE</sub> = 15 V	_	2.0	2.45	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10 V, V <sub>GE</sub> = 0, f = 1 MHz	_	3000	_	pF
Switching time	Turn-on delay time	t <sub>d (on)</sub>	Inductive Load $V_{CC} = 300 \text{ V, } I_{C} = 20 \text{ A}$ $V_{GG} = +15 \text{ V, } R_{G} = 33 \Omega} $ (Note 1) (Note 2)	_	0.06	_	μs
	Rise time	t <sub>r</sub>		_	0.04	_	
	Turn-on time	t <sub>on</sub>		_	0.17	_	
	Turn-off delay time	t <sub>d (off)</sub>		_	0.24	_	
	Fall time	t <sub>f</sub>		_	0.04	_	
	Turn-off time	t <sub>off</sub>		_	0.34	_	
Switching loss	Turn-on switching loss	E <sub>on</sub>		_	0.40	_	- mJ
	Turn-off switching loss	E <sub>off</sub>		_	0.43	_	
Peak forward voltage		V <sub>F</sub>	I <sub>F</sub> = 20 A, V <sub>GE</sub> = 0	_		2.1	٧
Reverse recovery time		t <sub>rr</sub>	I <sub>F</sub> = 20 A, di/dt = -100 A/μs	_	100	_	ns

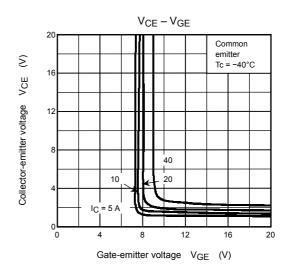
Note 1: Switching time measurement circuit and input/output waveforms

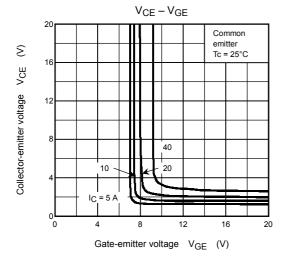


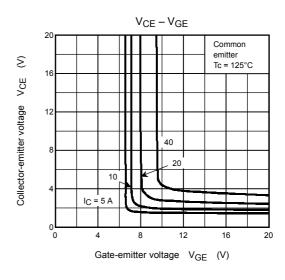
Note 2: Switching loss measurement waveforms

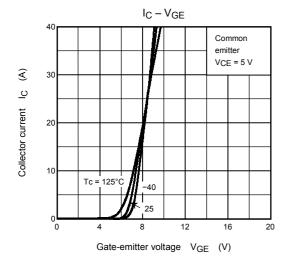


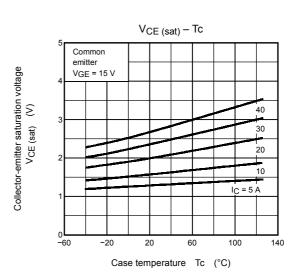


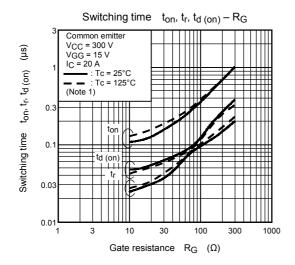


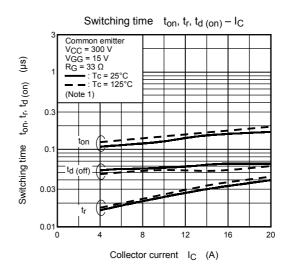


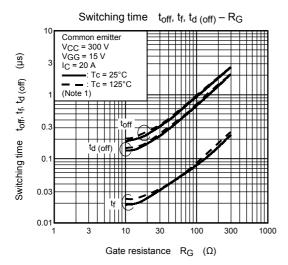


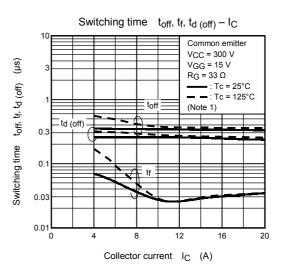


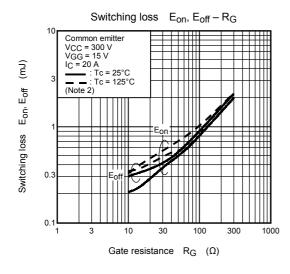


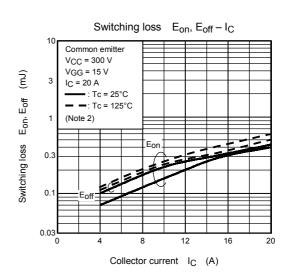


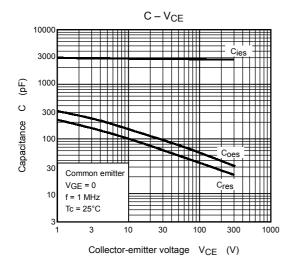


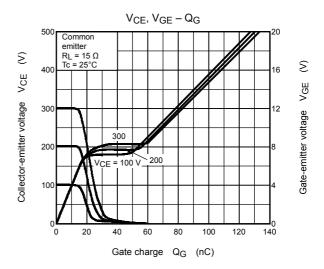


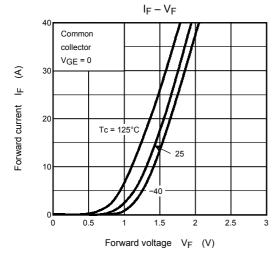


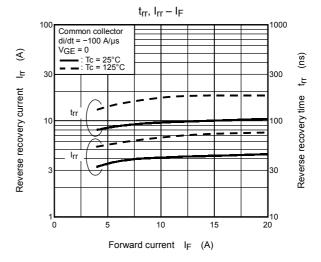


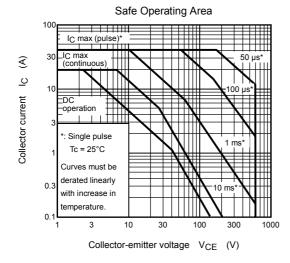


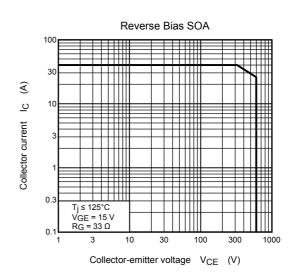


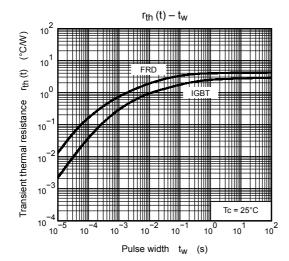












2002-04-08

#### RESTRICTIONS ON PRODUCT USE

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No
  responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
  rights of the third parties which may result from its use. No license is granted by implication or otherwise under
  any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.